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SN74AHC1G00 SINGLE 2-INPUT POSITIVE-NAND GATE

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Output voltage range, V _O (see Note 1)	
Input clamp current, I_{IK} ($V_I < 0$)	–20 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): DBV package	
DCK package	
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT	
VCC	Supply voltage		2	5.5	V	
		V _{CC} = 2 V	1.5			
VIH	High-level input voltage	$V_{CC} = 3 V$	2.1		V	
		V _{CC} = 5.5 V	3.85			
		V _{CC} = 2 V		0.5		
\vee_{IL}	Low-level input voltage	V _{CC} = 3 V		0.9	V	
		V _{CC} = 5.5 V		1.65		
VI	Input voltage		0	5.5	V	
VO	Output voltage		0	VCC	V	
		V _{CC} = 2 V		-50	μΑ	
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		-8	mA	
		$V_{CC} = 2 V$		50	μΑ	
IOL	Low-level output current	V_{CC} = 3.3 V ± 0.3 V		4	mA	
		V_{CC} = 5 V ± 0.5 V		8		
Δt/Δv	Input transition rise or fall rate	V_{CC} = 3.3 V ± 0.3 V		100	ns/V	
ΔųΔV		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		20	115/ V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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PARAMETER	TEST CONDITIONS	Vee	T _A = 25°C			MIN	MAX	UNIT
FARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX		IVIAA	UNIT
		2 V	1.9	2		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		
∨он		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		
	V_{OL} $I_{OL} = 50 \ \mu A$ $I_{OL} = 4 \ m A$	2 V			0.1		0.1	V
		3 V			0.1		0.1	
VOL		4.5 V			0.1		0.1	
		3 V			0.36		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.44	
lı	$V_{I} = V_{CC} \text{ or } GND$	0 V to 5.5 V			±0.1		±1	μΑ
ICC	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			1		10	μΑ
Ci	$V_{I} = V_{CC} \text{ or } GND$	5 V		2	10		10	pF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

Γ	PARAMETER	FROM	то	LOAD	Т	ן = 25°C	;	MIN	МАХ	UNIT	
	FARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX		MAA	UNIT	
Γ	^t PLH	A or P	A or B Y	A or B Y C _L = 15 pF		5.5	7.9	1	9.5	ns	
Γ	^t PHL	AUB				5.5	7.9	1	9.5	115	
Γ	^t PLH	A or D	Y	C: 50 pF		8	11.4	1	13		
Γ	^t PHL	A or B		Ť	Ť	C _L = 50 pF		8	11.4	1	13

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Τį	λ = 25°C	;	MIN	MAX	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIN	WAA	UNIT	
^t PLH	A or B	Y	C _L = 15 pF		3.7	5.5	1	6.5	ns	
^t PHL					3.7	5.5	1	6.5		
^t PLH	A or D	r B Y			5.2	7.5	1	8.5		
^t PHL	AUIB		C _L = 50 pF		5.2	7.5	1	8.5	ns	

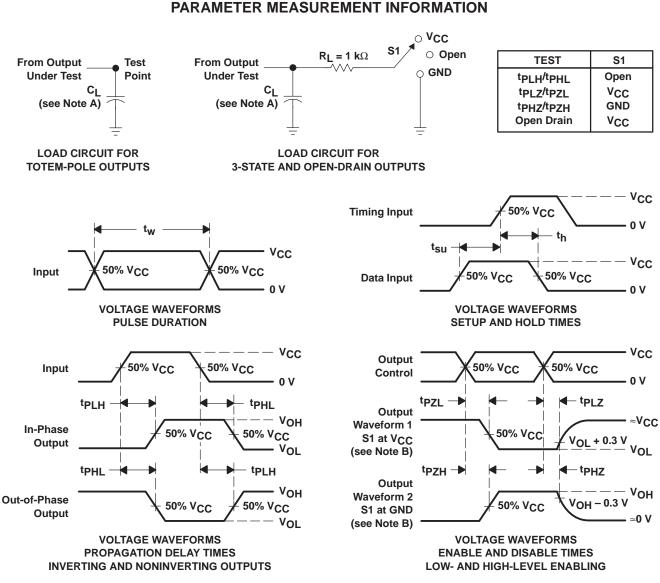
operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CO	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	9.5	pF



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NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.

D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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